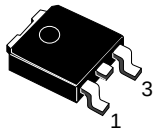
STGD3NB60SD

N-CHANNEL 3A - 600V - DPAK
PowerMESH™ IGBT

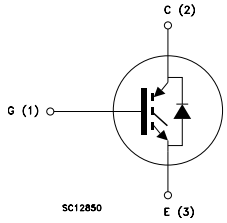
TYPE	V_{CES}	$V_{CE(sat)}$	I_C
STGD3NB60SD	600 V	< 1.5 V	3 A

- HIGH INPUT IMPEDANCE (VOLTAGE DRIVEN)
- VERY LOW ON-VOLTAGE DROP (V_{cesat})
- HIGH CURRENT CAPABILITY
- INTEGRATED WHEELING DIODE
- OFF LOSSES INCLUDE TAIL CURRENT



DPAK

INTERNAL SCHEMATIC DIAGRAM



DESCRIPTION

Using the latest high voltage technology based on a patented strip layout, STMicroelectronics has designed an advanced family of IGBTs, the PowerMESH™ IGBTs, with outstanding performances. The suffix “S” identifies a family optimized to achieve minimum on-voltage drop for low frequency applications (<1kHz).

APPLICATIONS

- MOTOR CONTROL
- GAS DISCHARGE LAMP
- STATIC RELAYS

ORDERING INFORMATION

SALES TYPE	MARKING	PACKAGE	PACKAGING
STGD3NB60SDT4	GD3NB60SD	DPAK	TAPE & REEL

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CES}	Collector-Emitter Voltage (V_{GS} = 0)	600	V
V_{GE}	Gate-Emitter Voltage	± 20	V
I_C	Collector Current (continuous) at T_C = 25°C	6	A
I_C	Collector Current (continuous) at T_C = 100°C	3	A
I_{CM} (▪)	Collector Current (pulsed)	25	A
P_{TOT}	Total Dissipation at T_C = 25°C	48	W
	Derating Factor	0.32	W/°C
T_{stg}	Storage Temperature	– 65 to 175	°C
T_j	Max. Operating Junction Temperature	175	°C

(●) Pulse width limited by safe operating area

THERMAL DATA

Rthj-case	Thermal Resistance Junction-case Max	3.125	°C/W
Rthj-amb	Thermal Resistance Junction-ambient Max	100	°C/W

ELECTRICAL CHARACTERISTICS (TCASE = 25 °C UNLESS OTHERWISE SPECIFIED)

OFF

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{BR(CES)}$	Collectro-Emitter Breakdown Voltage	I_C = 250 µA, V_{GE} = 0	600			V
I_{CES}	Collector cut-off (V_{GE} = 0)	V_{CE} = Max Rating, T_C = 25 °C V_{CE} = Max Rating, T_C = 125 °C			10 100	µA µA
I_{GES}	Gate-Emitter Leakage Current (V_{CE} = 0)	V_{GE} = ±20V , V_{CE} = 0			±100	nA

ON (1)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{GE(th)}$	Gate Threshold Voltage	V_{CE} = V_{GE}, I_C = 250µA	2.5		4.5	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	V_{GE} = 15V, I_C = 1.5 A V_{GE} = 15V, I_C = 3 A V_{GE} = 15V, I_C = 7 A, T_J =125 °C		1 1.2 1.1	1.5	V V V

DYNAMIC

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
g_{fs}	Forward Transconductance	V_{CE} = 10 V , I_C = 3 A	1.7	2.5		S
C_{ies}	Input Capacitance	V_{CE} = 25V, f = 1 MHz, V_{GE} = 0		255		pF
C_{oes}	Output Capacitance			30		pF
C_{res}	Reverse Transfer Capacitance			5.6		pF
Q_G Q_{GE} Q_{GC}	Total Gate Charge Gate-Emitter Charge Gate-Collector Charge	V_{CE} = 480 V, I_C = 3 A, V_{GE} = 15V		18 5.4 5.5	23	nC nC nC
I_{CL}	Latching Current	V_{clamp} = 380 V , Tj = 25°C R_G = 1KΩ	15			A

ELECTRICAL CHARACTERISTICS (CONTINUED)
SWITCHING ON

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$ t_r	Turn-on Delay Time Rise Time	V_{CC} = 480 V, I_C = 3 A R_G = 1KΩ , V_{GE} = 15 V		125 150		µs µs
$(di/dt)_{on}$ Eon	Turn-on Current Slope Turn-on Switching Losses	V_{CC}= 480 V, I_C = 3 A, R_G=1KΩ V_{GE} = 15 V, Tj = 125°C		50 1100		A/µs µJ

SWITCHING OFF

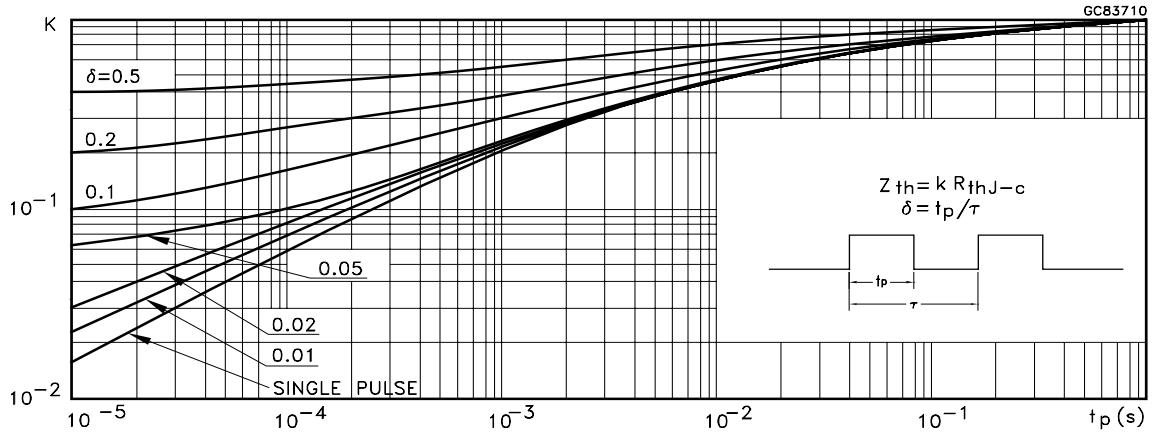
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
t_c $t_r(V_{off})$ $t_{d(on)}$ t_f E_{off}(**)	Cross-over Time Off Voltage Rise Time Delay Time Fall Time Turn-off Switching Loss	V_{cc} = 480 V, I_C = 3 A, R_{GE} = 1KΩ , V_{GE} = 15 V		1.8 1.0 3.4 0.72 1.15		µs µs µs µs mJ
t_c $t_r(V_{off})$ $t_{d(on)}$ t_f E_{off}(**)	Cross-over Time Off Voltage Rise Time Delay Time Fall Time Turn-off Switching Loss	V_{cc} = 480 V, I_C = 3 A, R_{GE} = 1KΩ , V_{GE} = 15 V, Tj = 125°C		2.8 1.45 3.6 1.2 1.8		µs µs µs µs mJ

COLLECTOR-EMITTER DIODE

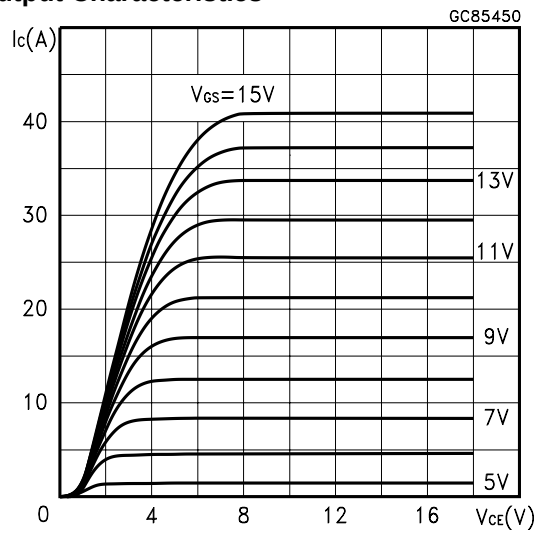
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_f I_{fm}	Forward Current Forward Current pulsed				3 25	A A
V_f	Forward On-Voltage	I_f = 3 A I_f = 1 A		1.55 1.15	1.9	V V
t_{rr} Q_{rr} I_{rrm}	Reverse Recovery Time Reverse Recovery Charge Reverse Recovery Current	I_f = 3 A ,V_R = 200 V, Tj =125°C, di/dt = 100A/µs		1700 4500 9.5		ns nC A

Note: 1. Pulsed: Pulse duration = 300 µs, duty cycle 1.5 %.
2. Pulse width limited by max. junction temperature.
(**) Losses also include the Tail (Jedec Standardization)

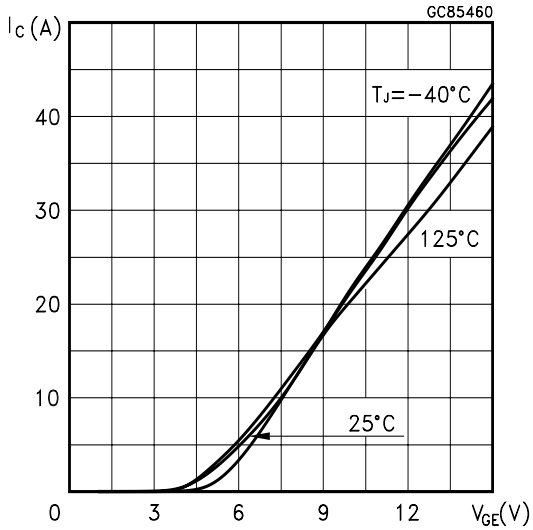
Thermal Impedance



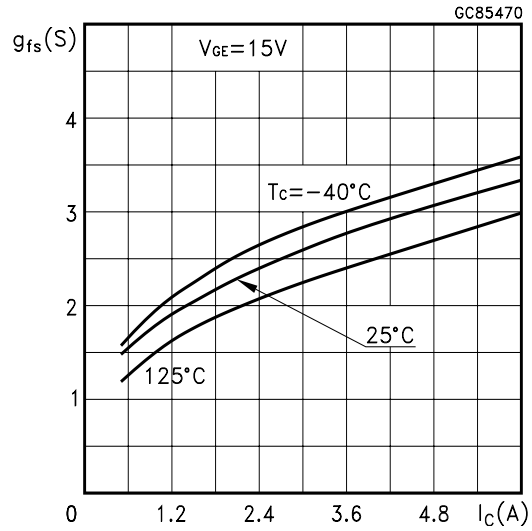
Output Characteristics



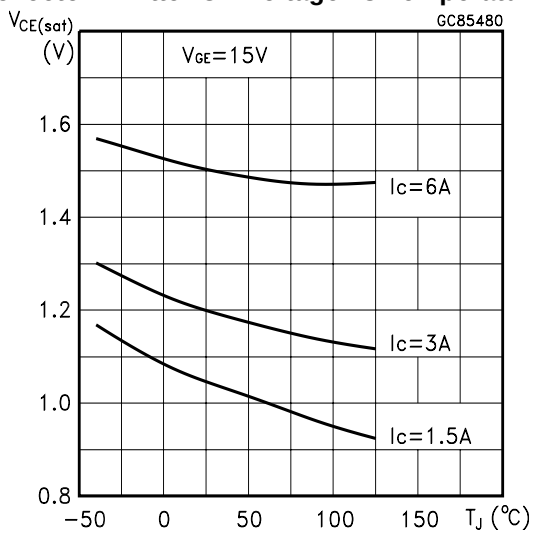
Transfer Characteristics



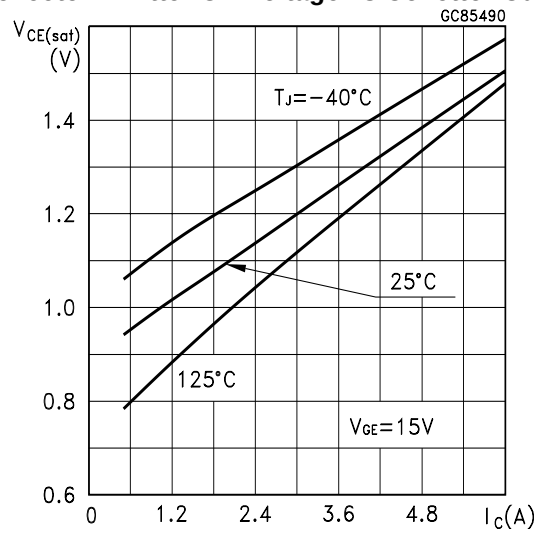
Transconductance



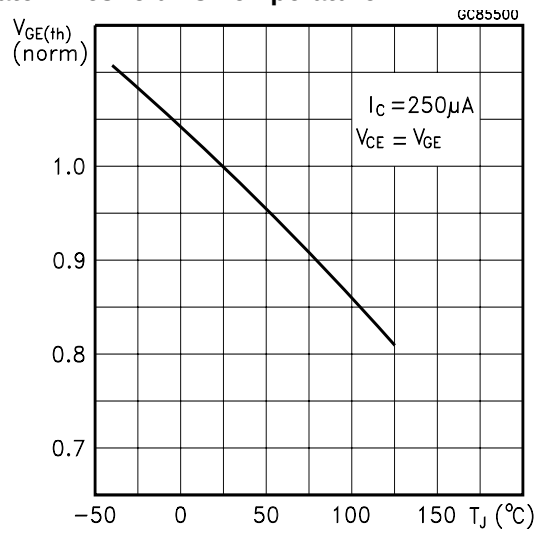
Collector-Emitter On Voltage vs Temperature



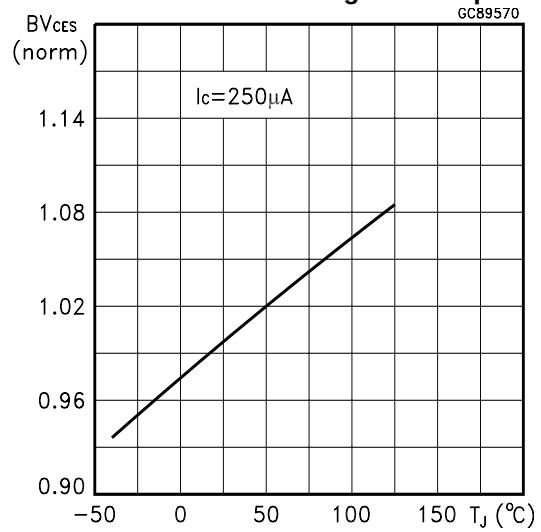
Collector-Emitter On Voltage vs Collettor Current



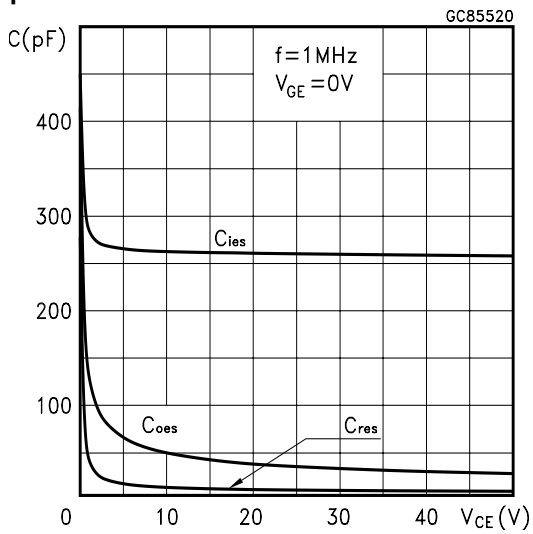
Gate Threshold vs Temperature



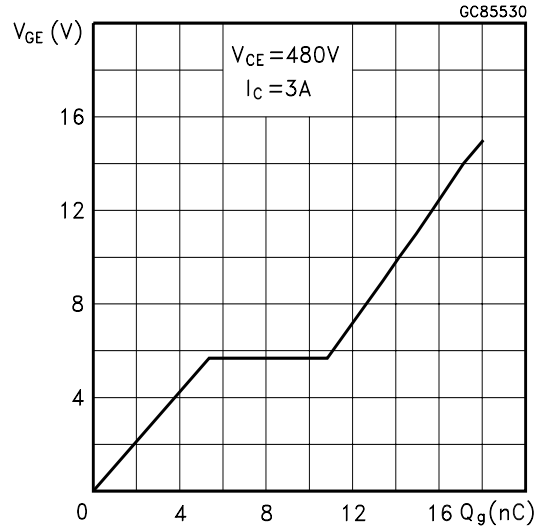
Normalized Breakdown Voltage vs Temperature



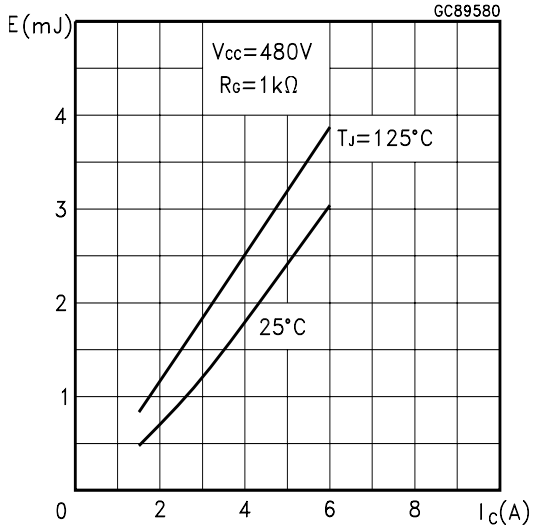
Capacitance Variations



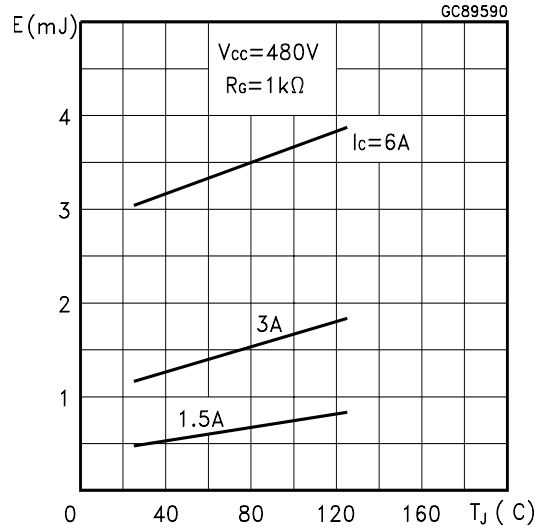
Gate Charge vs Gate-Emitter Voltage



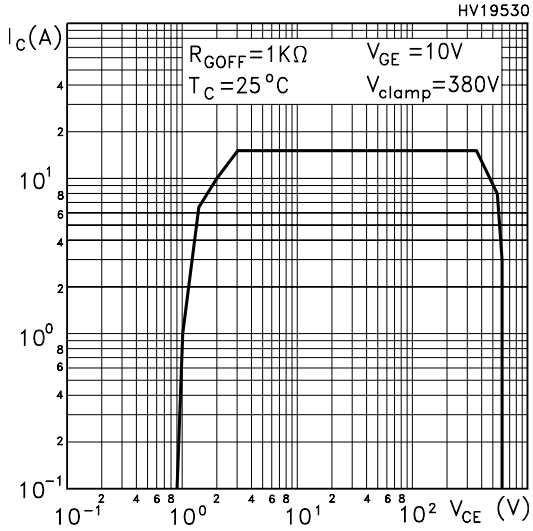
Off Losses vs Collector Current



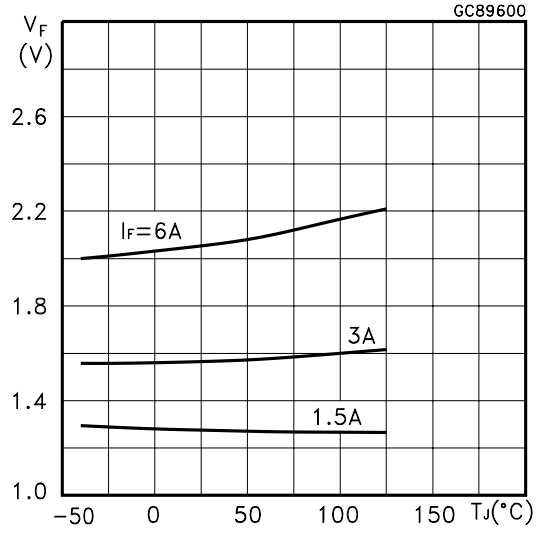
Off Losses vs Temperature



Switching Off Safe Operating Area



Diode Forward Voltage vs Tj



Diode Forward Voltage

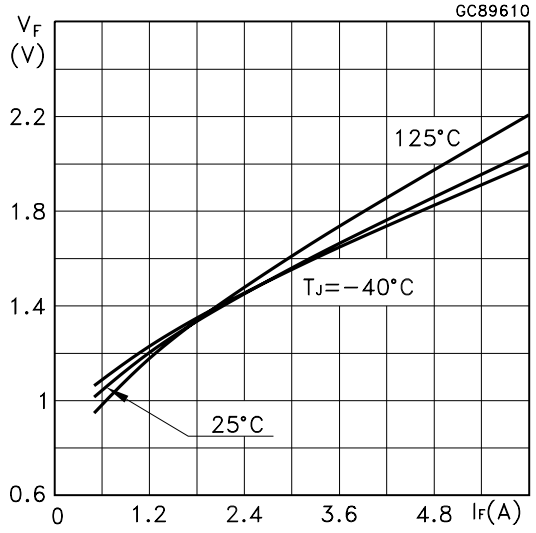


Fig. 1: Gate Charge test Circuit

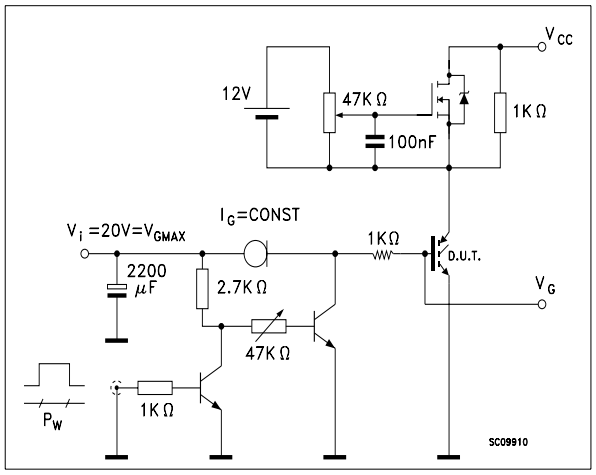
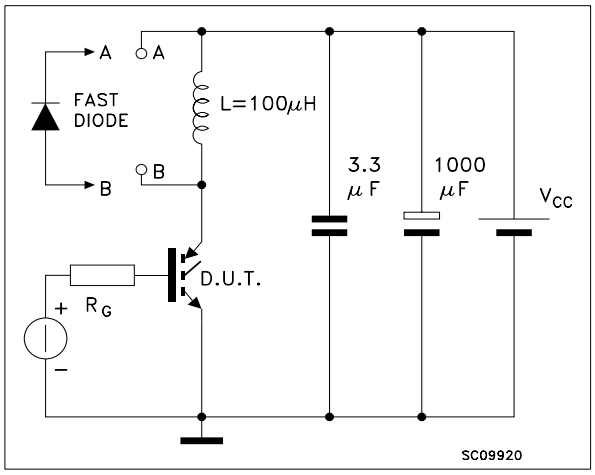
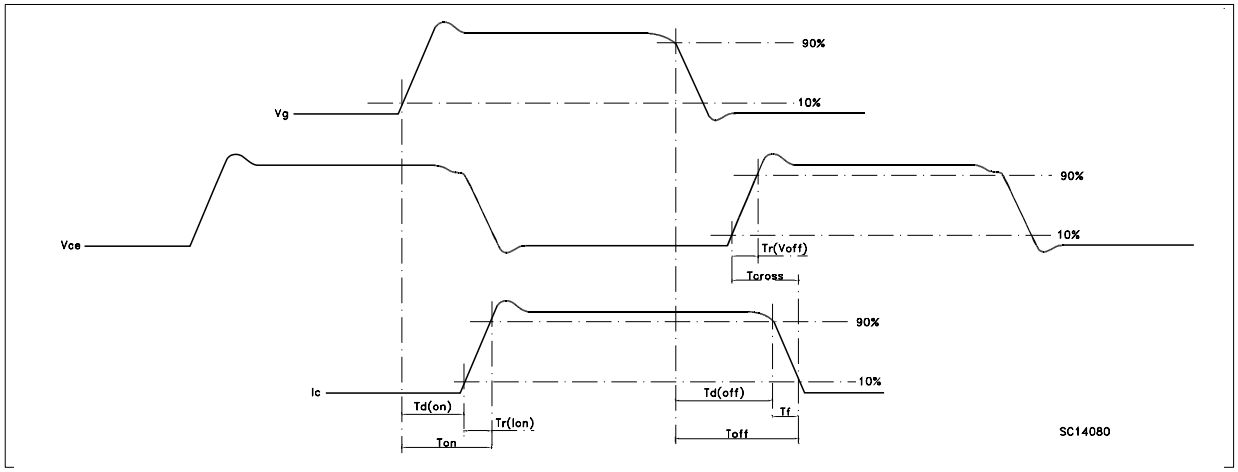


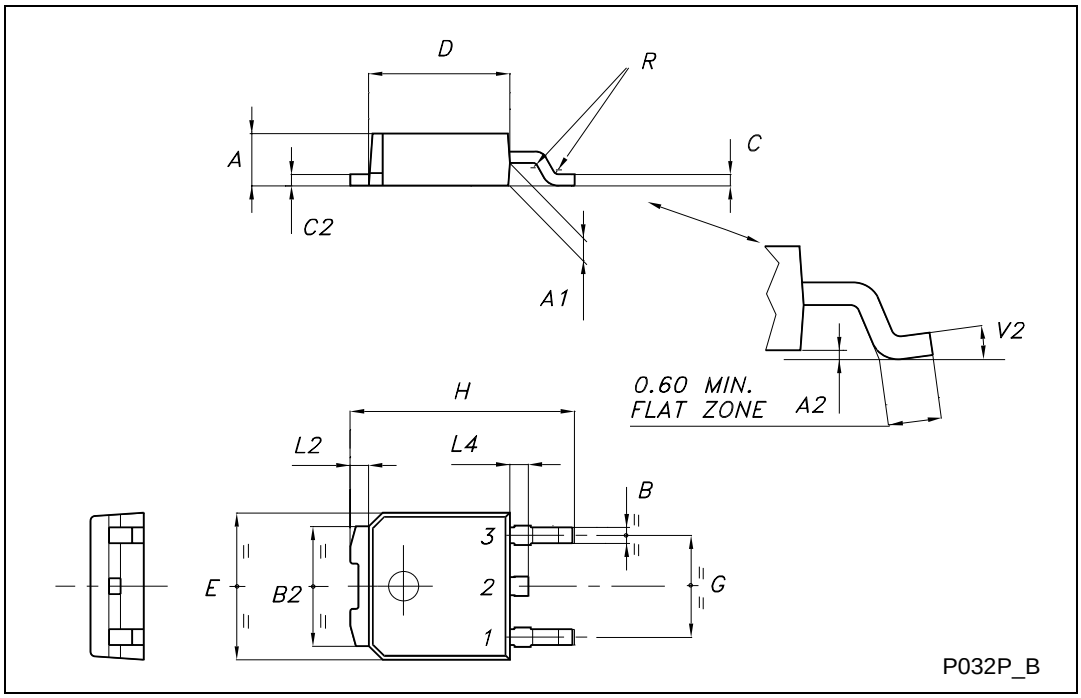
Fig. 2: Test Circuit For Inductive Load Switching



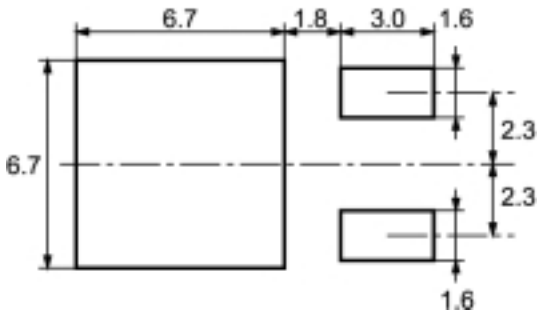


TO-252 (DPAK) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
B	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
C	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
H	9.35		10.10	0.368		0.398
L2		0.8			0.031	
L4	0.60		1.00	0.024		0.039
V2	0^o		8^o	0^o		0^o

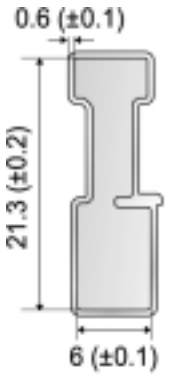


DPAK FOOTPRINT



All dimensions are in millimeters

TUBE SHIPMENT (no suffix)*

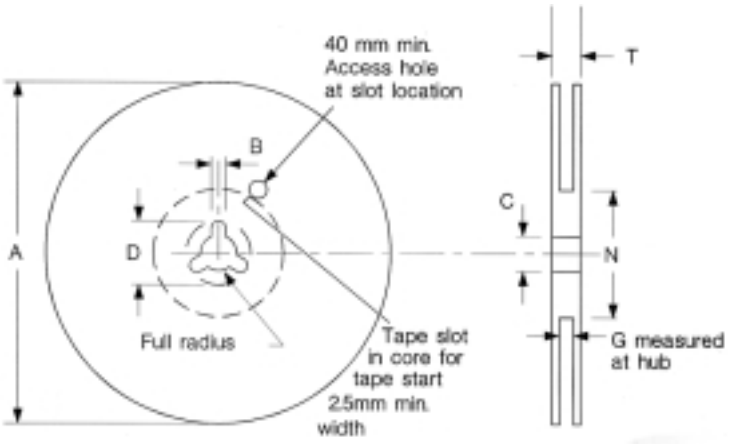


BASE QTY
75
BULK QTY
3000

Tube length 532 (±0.5)

All dimensions are in millimeters

TAPE AND REEL SHIPMENT (suffix "T4")*



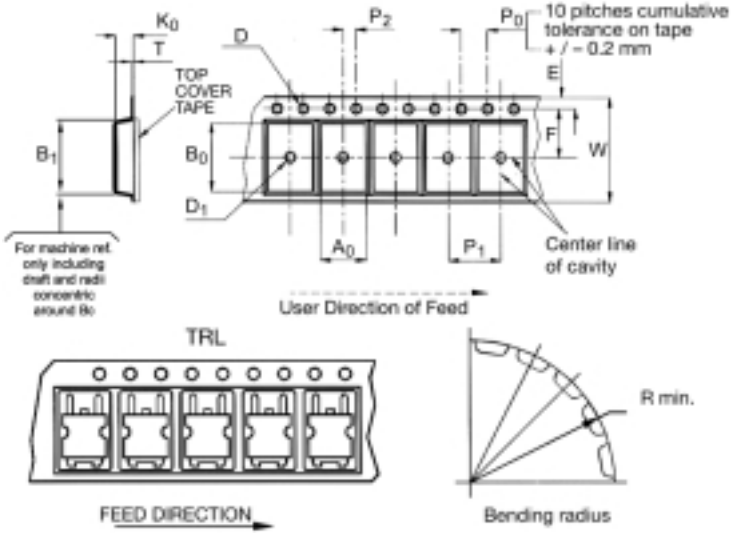
REEL MECHANICAL DATA

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A		330		12.992
B	1.5		0.059	
C	12.8	13.2	0.504	0.520
D	20.2		0.795	
G	16.4	18.4	0.645	0.724
N	50		1.968	
T		22.4		0.881

BASE QTY	BULK QTY
2500	2500

TAPE MECHANICAL DATA

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A0	6.8	7	0.267	0.275
B0	10.4	10.6	0.409	0.417
B1		12.1		0.476
D	1.5	1.6	0.059	0.063
D1	1.5		0.059	
E	1.65	1.85	0.065	0.073
F	7.4	7.6	0.291	0.299
K0	2.55	2.75	0.100	0.108
P0	3.9	4.1	0.153	0.161
P1	7.9	8.1	0.311	0.319
P2	1.9	2.1	0.075	0.082
R	40		1.574	
W	15.7	16.3	0.618	0.641



* on sales type